

Switch-mode Power Rectifiers

MUR1620CTG, MUR1640CTG, MUR1660CTG

These state-of-the-art devices are a series designed for use in switching power supplies, inverters and as free wheeling diodes.

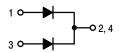
Features

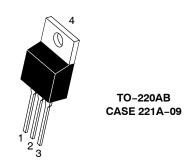
- Ultrafast 35 and 60 Nanosecond Recovery Times
- 175°C Operating Junction Temperature
- Popular TO-220 Package
- Epoxy Meets UL 94 V-0 @ 0.125 in
- High Temperature Glass Passivated Junction
- High Voltage Capability to 600 V
- Low Leakage Specified @ 150°C Case Temperature
- Current Derating @ Both Case and Ambient Temperatures
- These are Pb-Free Devices*

Mechanical Characteristics:

- Case: Epoxy, Molded
- Weight: 1.9 Grams (Approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds

ULTRAFAST RECTIFIERS 16 AMPERES, 100-600 VOLTS





MARKING DIAGRAM



A = Assembly Location

Y = Year WW = Work Week U16xx = Device Code

G

xx = 10, 15, 20, 40 or 60 = Pb–Free Package = Diode Polarity

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 7 of this data sheet.

NOTE: Some of the device on this data sheet have been **DISCONTINUED**. Please refer to the table on page 7

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^{*}For additional information on our Pb-Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

MAXIMUM RATINGS

		MUR16					
Rating	Symbol	10CT	15CT	20CT	40CT	60CT	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	100	150	200	400	600	V
	I _{F(AV)}	8.0 16		Α			
Peak Rectified Forward Current Per Diode Leg (Rated V _R , Square Wave, 20 kHz), T _C = 150°C	I _{FM}	16			Α		
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)				100			Α
Operating Junction Temperature and Storage Temperature	T _J , T _{stg}		-	65 to +1	75		°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS (Per Diode Leg)

Parameter	Symbol	Value		Unit
Maximum Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	3.0	2.0	°C/W

ELECTRICAL CHARACTERISTICS (Per Diode Leg)

Characteristic	Symbol	1620	1640	1660	Unit
Maximum Instantaneous Forward Voltage (Note 1) ($i_F = 8.0 \text{ A}, T_C = 150^{\circ}\text{C}$) ($i_F = 8.0 \text{ A}, T_C = 25^{\circ}\text{C}$)	VF	0.895 0.975	1.00 1.30	1.20 1.50	V
Maximum Instantaneous Reverse Current (Note 1) (Rated DC Voltage, T _C = 150°C) (Rated DC Voltage, T _C = 25°C)	i _R	250 5.0	50 1		μΑ
Maximum Reverse Recovery Time $ \begin{aligned} (I_F = 1.0 \text{ A, di/dt} = 50 \text{ A/}\mu\text{s}) \\ (I_F = 0.5 \text{ A, }I_R = 1.0 \text{ A, }I_{REC} = 0.25 \text{ A}) \end{aligned} $	t _{rr}	35 25	6	-	ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

^{1.} Pulse Test: Pulse Width = 300 μs, Duty Cycle ≤[2.0%

MUR1610CT, MUR1615CT, MUR1620CT

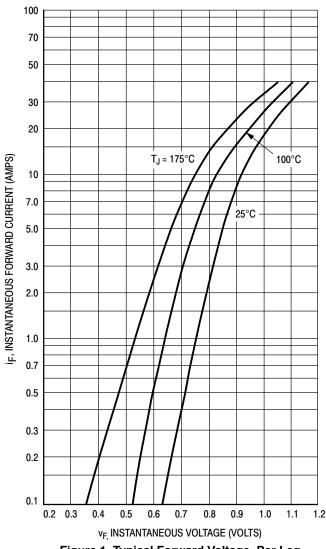


Figure 1. Typical Forward Voltage, Per Leg

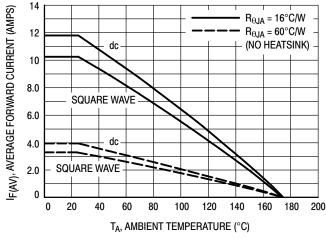


Figure 4. Current Derating, Ambient, Per Leg

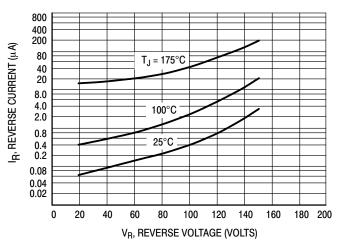


Figure 2. Typical Reverse Current, Per Leg*

* The curves shown are typical for the highest voltage device in the voltage grouping. Typical reverse current for lower voltage selections can be estimated from these same curves if V_R is sufficiently below rated V_R .

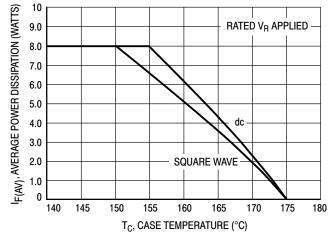


Figure 3. Current Derating, Case, Per Leg

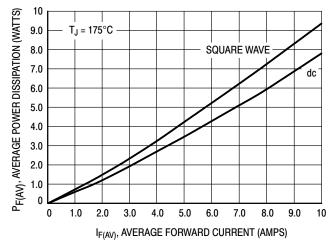


Figure 5. Power Dissipation, Per Leg

MUR1640CT

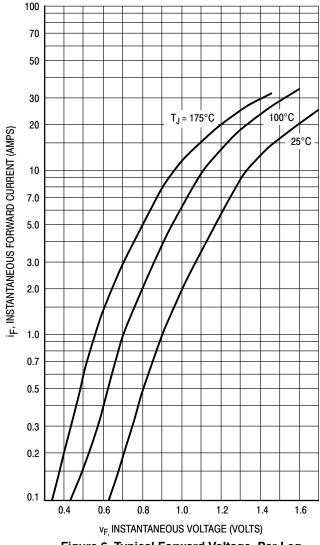


Figure 6. Typical Forward Voltage, Per Leg

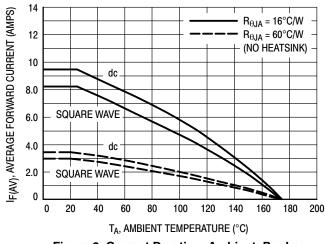


Figure 9. Current Derating, Ambient, Per Leg

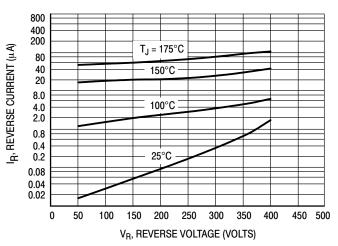


Figure 7. Typical Reverse Current, Per Leg*

* The curves shown are typical for the highest voltage device in the voltage grouping. Typical reverse current for lower voltage selections can be estimated from these curves if V_R is sufficiently below rated V_R .

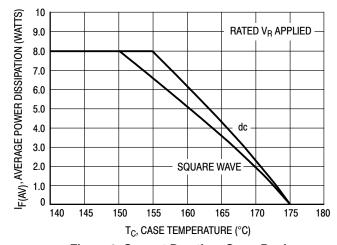


Figure 8. Current Derating, Case, Per Leg

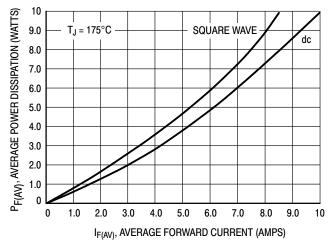


Figure 10. Power Dissipation, Per Leg

MUR1660CT

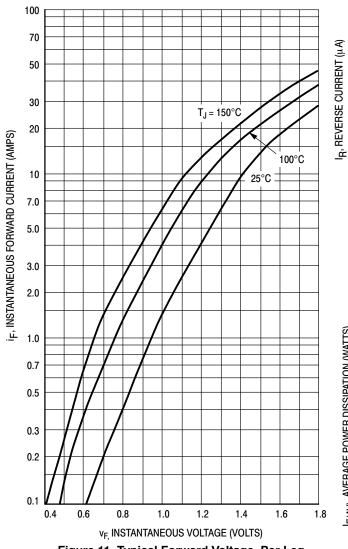


Figure 11. Typical Forward Voltage, Per Leg

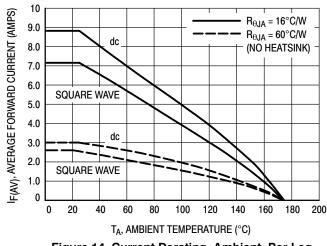


Figure 14. Current Derating, Ambient, Per Leg

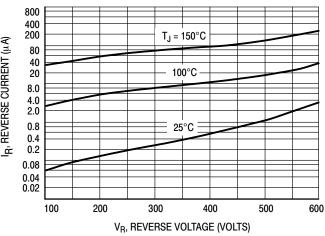


Figure 12. Typical Reverse Current, Per Leg*

* The curves shown are typical for the highest voltage device in the voltage grouping. Typical reverse current for lower voltage selections can be estimated from these same curves if V_R is sufficiently below rated V_R .

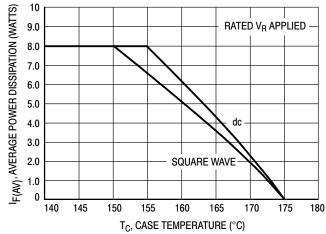


Figure 13. Current Derating, Case, Per Leg

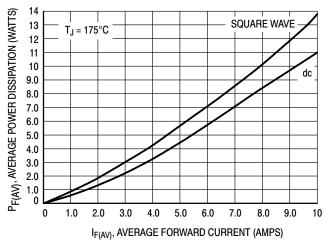


Figure 15. Power Dissipation, Per Leg

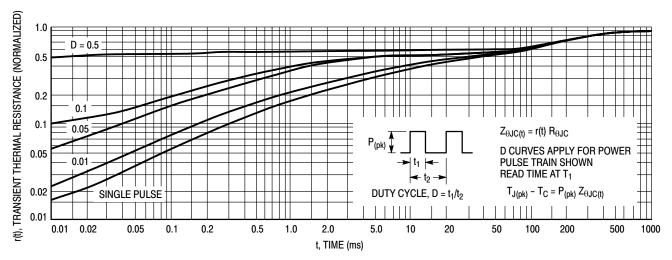


Figure 16. Thermal Response

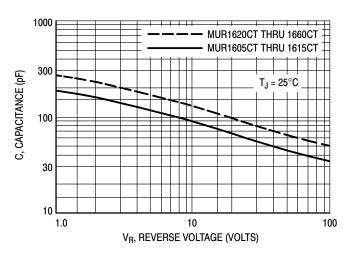


Figure 17. Typical Capacitance, Per Leg

ORDERING INFORMATION

Device	Package	Shipping [†]
MUR1620CTG	TO-220 (Pb-Free)	
MUR1640CTG	TO-220 (Pb-Free)	50 Units / Rail
MUR1660CTG	TO-220 (Pb-Free)	

DISCONTINUED (Note 2)

Device	Package	Shipping [†]
MUR1610CTG	TO-220 (Pb-Free)	50 Unito / Doil
MUR1615CTG	TO-220 (Pb-Free)	50 Units / Rail

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

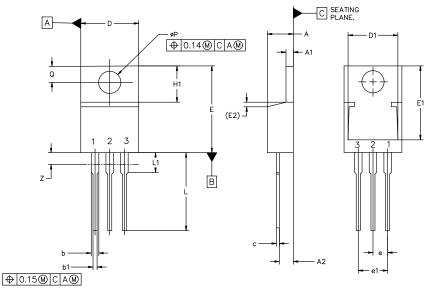
^{2.} **DISCONTINUED:** This device is not recommended for new design. Please contact your **onsemi** representative for information. The most current information on this device may be available on www.onsemi.com.





TO-220-3 10.10x15.12x4.45, 2.54P CASE 221A **ISSUE AL**

DATE 05 FEB 2025



MILLIMETERS						
DIM	MIN	NOM	MAX			
Α	4.07	4.45	4.83			
A1	1.15	1.28	1.41			
A2	2.04	2.42	2.79			
Ь	1.15	1.34	1.52			
b1	0.64	0.80	0.96			
O	0.36	0.49	0.61			
D	9.66	10.10	10.53			
D1	8.43	8.63	8.83			
E	14.48	15.12	15.75			
E1	12.58	12.78	12.98			
E2	E2 1.27 REF					

MILLIMETERS						
DIM	MIN	NOM	MAX			
е	2.42	2.54	2.66			
e1	4.83	5.08	5.33			
H1	5.97	6.22	6.47			
L	12.70	13.49	14.27			
L1	2.80	3.45	4.10			
Q	2.54	2.79	3.04			
ØΡ	3.60	3.85	4.09			
Z		-,	3.48			

NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018.
 2. CONTROLLING DIMENSION: MILLIMETERS.
 3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

STYLE 1:		STYLE 2:		STYLE 3:		STYLE 4:	
PIN 1.	BASE	PIN 1.	BASE	PIN 1.	CATHODE	PIN 1.	MAIN TERMINAL 1
2.	COLLECTOR	2.	EMITTER	2.	ANODE	2.	MAIN TERMINAL 2
3.	EMITTER	3.	COLLECTOR	3.	GATE	3.	GATE
4.	COLLECTOR	4.	EMITTER	4.	ANODE	4.	MAIN TERMINAL 2
STYLE 5:		STYLE 6:		STYLE 7:		STYLE 8:	
PIN 1.	GATE	PIN 1.	ANODE	PIN 1.	CATHODE	PIN 1.	CATHODE
2.	DRAIN	2.	CATHODE	2.	ANODE	2.	ANODE
3.	SOURCE	3.	ANODE	3.	CATHODE	3.	EXTERNAL TRIP/DELAY
4.	DRAIN	4.	CATHODE	4.	ANODE	4.	ANODE
STYLE 9:		STYLE 10:		STYLE 11:		STYLE 12:	
PIN 1.	GATE	PIN 1.	GATE	PIN 1.	DRAIN	PIN 1.	MAIN TERMINAL 1
2.	COLLECTOR	2.	SOURCE	2.	SOURCE	2.	MAIN TERMINAL 2
3.	EMITTER	3.	DRAIN	3.	GATE	3.	GATE
4.	COLLECTOR	4.	SOURCE	4.	SOURCE	4.	NOT CONNECTED

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DESCRIPTION:	TO-220-3 10.10x15.12x4.45, 2.54P		PAGE 1 OF 1	

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